

| Session | Session 名 | Name | Affiliation | Abstract Title | Room | 講演番号 | 講演日 | 時間 | |
|---------|-----------------|---|---------------------------|--|---|--------|---------|---------------|-------------|
| 1 | Plenary | Plenary Lecture | Jiro Kasahara | Nagoya University | Detonation-Engine-System Space Flight Experiments and Fundamental Researches | Room A | 04aA01P | March 4, 2023 | 10:10-11:10 |
| 2 | Keynote | Keynote Lecture | Yoshihide Kihara | Tokyo Electron Miyagi Ltd. | Novel Ultra-High Productivity and High Aspect Ratio Dielectric Etch Technology for 3D NAND Flash Memory | Room A | 07aA08K | March 7, 2024 | 11:45-12:35 |
| 3 | Keynote | Keynote Lecture | Uros Cvelbar | Jožef Stefan Institute | Hybrid Carbon Nanostructures for Advanced Energy Storage | Room A | 04pA03K | March 4, 2023 | 12:10-13:00 |
| 4 | Keynote | Keynote Lecture | Kevin Chen | The Hong Kong University of Science and Technology | Unlocking the Full Potential of GaN for Power Devices and Ics | Room A | 05aA06K | March 5, 2024 | 11:30-12:20 |
| 5 | Keynote | Keynote Lecture | Vandana Miller | Drexel University, USA | Non-Thermal Plasma as a Therapy for Viral Infections | Room A | 05pA07K | March 5, 2024 | 12:20-13:10 |
| 6 | Tutorial | Tutorial Lecture | Bruno Daudin | CEA-Grenoble | Overview of III-Nitrides Nanostructures Growth Using Plasma-Assisted Molecular Beam Epitaxy: From Quantum Wells and Quantum Dots to Nanowire Heterostructures | Room A | 04aA02T | March 3, 2024 | 14:15-15:15 |
| 7 | Tutorial | Tutorial Lecture | Daniel Chua | National University of Singapore | Nanotechnology: The Science Behind It and the Technology Ahead | Room A | 04aA03T | March 3, 2024 | 15:30-16:30 |
| 8 | Tutorial | Tutorial Lecture | David B. Graves | Princeton University, USA | Biological Effects of Nonequilibrium Plasma | Room A | 04aA04T | March 3, 2024 | 16:45-17:45 |
| 9 | Invited | Plasma Science & Technologies 4 | Naoto Kodama | Nagoya University | Development of Electrical Circuit Protection Device Based on Gas properties Analysis of High-Temperature Arc and Hot Gas | Room B | 05pB08I | March 5, 2024 | 14:30-15:00 |
| 10 | Invited | Plasma Science & Technologies 3 | Kazunori Takahashi | Tohoku University | Plasma Dynamics in a Magnetic Nozzle Radiofrequency Plasma Thruster | Room B | 05aB01I | March 5, 2024 | 9:30-10:00 |
| 11 | Invited | Plasma Science & Technologies 5 | Oi Lun (Helena) Li | Pusan National University | Plasma-Engineered Negative Surface-Mediated Catalysts for Seawater-Based Electrochemical Devices | Room B | 06aB01I | March 6, 2024 | 9:30-10:00 |
| 12 | Invited | Plasma Science & Technologies 3 | Po-Yu Chang | National Cheng-Kung University | Development of Pulsed-Plasma Thruster using an Unbalanced Theta Pinch | Room B | 05aB02I | March 5, 2024 | 10:00-10:30 |
| 13 | Invited | Plasma Science & Technologies 6 | Ying-Hao Liao | National Yang Ming Chiao Tung University | Materials and Process innovation to Enable 3-Dimensional Semiconductor Devices | Room B | 07aB01I | March 7, 2024 | 9:30-10:00 |
| 14 | Invited | Plasma Science & Technologies 1 | Ryo Ono | The University of Tokyo | Measurement of Single-Filament Streamer Discharge for Comparison with Two-Dimensional Simulation | Room B | 04pB04I | March 4, 2024 | 14:40-15:10 |
| 15 | Invited | Nitride Semiconductors 1 | Hironori Okumura | University of Tsukuba | High-Temperature and High-Power Devices Using AlN | Room D | 04pD05I | March 4, 2024 | 15:10-15:40 |
| 16 | Invited | Nitride Semiconductors 1 | Yongzhao YAO | Japan Fine Ceramics Center | Visualization of Structural Defects In B-Ga ₂ O ₃ Using Synchrotron X-Ray Techniques For Power-Device Application | Room D | 04pD04I | March 4, 2024 | 14:40-15:10 |
| 17 | Invited | Nitride Semiconductors 4 | Shuhei Ichikawa | Osaka University | Hybrid Integration of Eu-Doped GaN and InGaN LEDs towards Ultrahigh Definition Micro-LED Display | Room D | 06aD02I | March 6, 2024 | 10:15-10:45 |
| 18 | Invited | Nitride Semiconductors 2 | Makoto Kasu | Saga University | Diamond High Power and Voltage MOSFETs:Physics, Fabrication, Static and Dynamic Characterization | Room D | 05aD03I | March 5, 2024 | 10:15-10:45 |
| 19 | Invited | Nitride Semiconductors 3 | Masataka Imura | National Institute for Materials Science (NIMS) | Development of Highly Tolerant Diamond Schottky Barrier Photodiodes for Deep-Ultraviolet Xenon Excimer Lamp and Protons Detection | Room D | 05pD09I | March 5, 2024 | 14:45-15:15 |
| 20 | Invited | Nitride Semiconductors 2 | Yoshitaka Taniyasu | NTT Basic Research Laboratories | Recent Progress of AlN Based Ultra-Wide Bandgap Semiconductor Devices | Room D | 05aD02I | March 5, 2024 | 9:45-10:15 |
| 21 | Invited | Nitride Semiconductors 4 | Ziyi Zhang | Asahi Kasei | AlGaN Based Laser Diode of UV-C Wavelength | Room D | 06aD01I | March 6, 2024 | 9:45-10:15 |
| 22 | Invited | Nitride Semiconductors 3 | Shinya Ohmagari | National Institute of Advanced Industrial Science and Technology | Recalibration-Free Single-Use Concept Diamond-Based Electronic Tongue: Fast, Single-Drop, Portable Fingerprinting Analysis | Room D | 05pD08I | March 5, 2024 | 14:15-14:45 |
| 23 | Invited | Nitride Semiconductors 3 | Alessandro Floriduz | Nano Federal Institute of Technology in Lancaster (NFTEL), Lancaster | Direct High-Temperature MOCVD Growth of High-Quality GaN on ScAlMgO ₃ : A Ppathway for High Performance Devices | Room D | 05pD10I | March 5, 2024 | 15:15-15:45 |
| 24 | Invited | Nitride Semiconductors 2 | Srabanti Chowdhury | Stanford University | Diamond on GaN Integration at Low Temperatures with Remarkably High Thermal Conductivity and Low Thermal Boundary Resistance | Room D | 05aD01I | March 5, 2024 | 9:15-9:45 |
| 25 | Invited | Nanomaterials 5 | Jun Xu | Nantong University/Nanjing University | High-Efficient Absorption and Modulation of Solar Spectrum via Si-Based Hybrid Nanostructures | Room C | 06aC01I | March 6, 2024 | 9:30-10:00 |
| 26 | Invited | Nanomaterials 1 | Hiroharu Kawasaki | National Institute of Technology, Saaboo College | Elemental Gradient Functional Thin Films Preparation by Sputtering with Mixed Powder Targets | Room C | 04pC04I | March 4, 2024 | 14:40-15:10 |
| 27 | Invited | Nanomaterials 6 | Masashi Akabori | Japan Advanced Institute of Science and Technology | Magnetic Domain Control of CoFe/MgO Nanolayer Patterns for III-V Semiconductor Spintronic Device Applications | Room C | 06pC11I | March 6, 2024 | 16:40-17:10 |
| 28 | Invited | Nanomaterials 3 | Takayuki Hoshino | Nagoya University | Virtual Cathode Display for Biomolecules and Living Cells | Room C | 05aC01I | March 5, 2024 | 9:30-10:00 |
| 29 | Invited | Nanomaterials 4 | Kazuhiro Gotoh | Niigata University | Development of Silicon Nanocrystals/Silicon Oxide Composite Films for Application to Crystalline Silicon Solar Cells | Room C | 05pC02I | March 5, 2024 | 14:30-15:00 |
| 30 | Invited | Nanomaterials 7 | Hung-Yin Tsai | National Tsing Hua University | Study on Fabrication of Force Transducer Based on Carbon Nano-Flake Balls | Room C | 07aC01I | March 7, 2024 | 9:30-10:00 |
| 31 | Invited | Nanomaterials 2 | Daniel Chua | National University of Singapore | Plasma-based fabrication of low-dimensional Carbon and Metal Dichalcogenide Nanocomposites for Electronics and Green Applications. | Room C | 04pC09I | March 4, 2024 | 18:00-18:30 |
| 32 | Invited | Bio Applications 3 | Yun-Chien Cheng | National Yang Ming Chiao Tung University | Atmospheric-Pressure Plasma Effects on Cancer Cells and Equivalent Circuit Analysis to Improve Plasma Stability | Room E | 07aE01I | March 7, 2024 | 9:30-10:00 |
| 33 | Invited | Bio Applications 1 | Sang Hye Ji | Korea Institute of Fusion Energy | Biodegradation of Low-Density Polyethylene by Plasma-Activated <i>Bacillus</i> Strain | Room E | 05aE01I | March 5, 2024 | 9:30-10:00 |
| 34 | Invited | Bio Applications 2 | Kathrina Lois Magat Taaca | University of the Philippines Diliman | Utilizing Atmospheric Pressure Plasma in Developing Hydrogel Biomaterials | Room E | 05pE08I | March 5, 2024 | 14:30-15:00 |
| 35 | Topical Session | Topical session(APSP-13): Semiconductor | Samuel Chiu | TSMC Account / Applied Materials Taiwan | Materials and Process innovation to Enable 3-Dimensional Semiconductor Devices | Room A | 06aA08I | March 6, 2024 | 11:45-12:20 |
| 36 | Topical Session | Topical session(APSP-13): Semiconductor | Jenq-Gong Duh | National Tsing Hua University,Hsinchu,Taiwan | Solder joint reliability in microbump for microelectronic packages via thin film metallization and doping by surface modification techniques | Room A | 06pA09I | March 6, 2024 | 12:20-12:55 |
| 37 | ISPlasma Prize | Plasma Prize Lecture | Petoro Favia | University of Bari Aldo Moro | Gas Plasmas in Life Sciences, from Biomaterials to Agriculture | Room A | | March 4, 2024 | 11:10-12:10 |
| 38 | Hall of Fame | Plasma Materials Science Hall of Fame Prize Lecture 1 | Uwe Czarnetzki | Ruhr University Bochum | | Room A | | March 6, 2024 | 14:40-15:30 |
| 39 | Hall of Fame | Plasma Materials Science Hall of Fame Prize Lecture 2 | Kazuuo Terashima | The University of Tokyo | | Room A | | March 6, 2024 | 15:30-16:20 |